Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic and metal
Overall Length:
0.094 inches
Overall Diameter:
0.123 inches
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 breakdown voltage, dc
Current Rating Per Characteristic:
100.00 microamperes forward current, average peak
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
2 ferrule
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0